

FG4000CX-90DA

HIGH POWER INVERTER USE
PRESS PACK TYPE

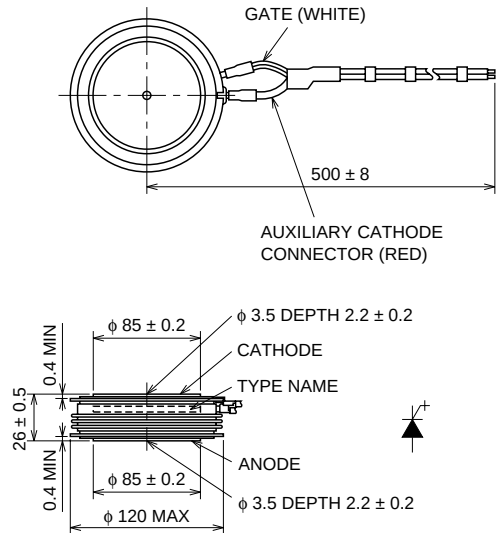
FG4000CX-90DA



- ITQRM Repetitive controllable on-state current 4000A
- IT(AV) Average on-state current 1200A
- VDRM Repetitive peak off state voltage 4500V
- Anode short type

OUTLINE DRAWING

Dimensions in mm



APPLICATION

Inverters, D.C. choppers, Induction heaters, D.C. to D.C. converters.

MAXIMUM RATINGS

Symbol	Parameter	Voltage class	Unit
		90DA	
VRRM	Repetitive peak reverse voltage	19	V
VRSM	Non-repetitive peak reverse voltage	19	V
VR(DC)	DC reverse voltage	19	V
VDRM	Repetitive peak off-state voltage*	4500	V
VDSM	Non-repetitive peak off-state voltage*	4500	V
VD(DC)	DC off-state voltage*	2500	V

* : VGK = -2V

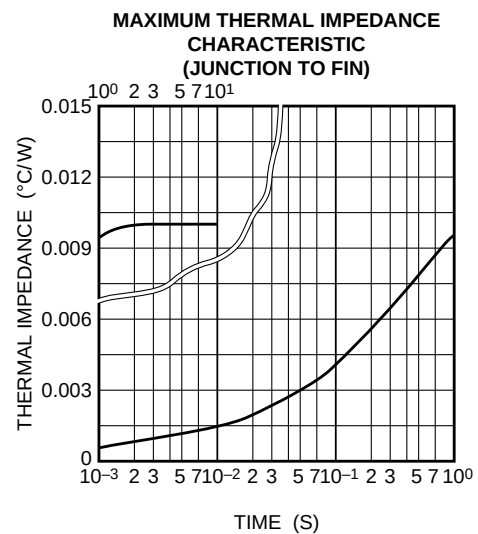
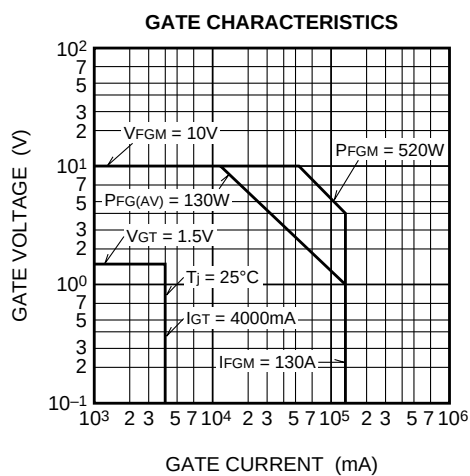
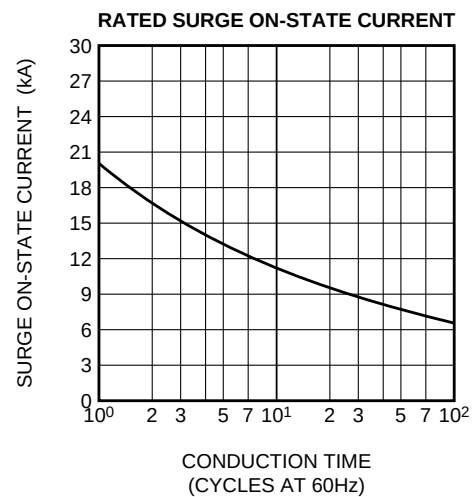
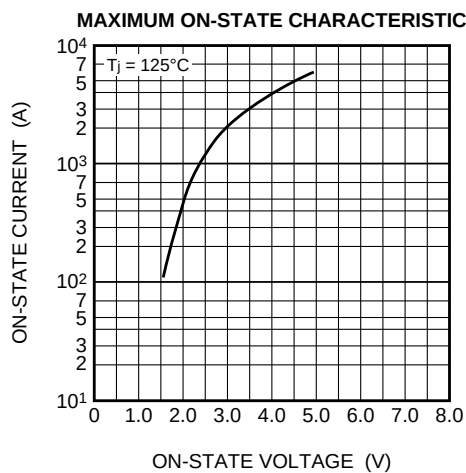
Symbol	Parameter	Conditions	Ratings	Unit
ITQRM	Repetitive controllable on-state current	V _{DM} = 3375V, T _J = 125°C, C _s = 5.0μF, L _s = 0.2μH	4000	A
IT(RMS)	RMS on-state current		1880	A
IT(AV)	Average on-state current	f = 60Hz, sine wave θ = 180°, T _r = 78°C	1200	A
ITSM	Surge (non-repetitive) on-state current	One half cycle at 60Hz	20	kA
I ² t	Current-squared, time integration	One cycle at 60Hz	1.7 × 10 ⁶	A ² s
diT/dt	Critical rate of rise of on-state current	V _D = 3400V, I _{GM} = 40A, T _J = 125°C	500	A/μs
VFGM	Peak forward gate voltage		10	V
VRGM	Peak reverse gate voltage		19	V
IFGM	Peak forward gate current		130	A
IRGM	Peak gate reverse current		1100	A
PFGM	Peak forward gate power dissipation		520	W
PRGM	Peak reverse gate power dissipation		33	kW
PFG(AV)	Average forward gate power dissipation		130	W
PRG(AV)	Average reverse gate power dissipation		300	W
T _J	Junction temperature		-40 ~ +125	°C
T _{stg}	Storage temperature		-40 ~ +150	°C
—	Mounting force required	Recommended value 47	38 ~ 54	kN
—	Weight	Standard value	1600	g

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ELECTRICAL CHARACTERISTICS

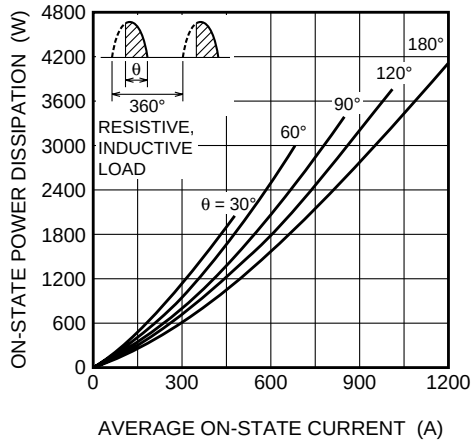
Symbol	Parameter	Test conditions	Limits			Unit
			Min	Typ	Max	
V_{TM}	On-state voltage	$T_j = 125^\circ\text{C}$, $I_{TM} = 4000\text{A}$, Instantaneous measurment	—	—	4.0	V
I_{RRM}	Repetitive peak reverse current	$T_j = 125^\circ\text{C}$, V_{RRM} Applied	—	—	100	mA
I_{DRM}	Repetitive peak off-state current	$T_j = 125^\circ\text{C}$, V_{DRM} Applied, $V_{GK} = -2\text{V}$	—	—	150	mA
I_{RG}	Reverse gate current	$T_j = 125^\circ\text{C}$, $V_{RG} = 19\text{V}$	—	—	100	mA
dv/dt	Critical rate of rise of off-state voltage	$T_j = 125^\circ\text{C}$, $V_D = 2250\text{V}$, $V_{GK} = -2\text{V}$	1000	—	—	V/ μs
t_{gt}	Turn-on time	$T_j = 125^\circ\text{C}$, $I_{TM} = 4000\text{A}$, $I_{GM} = 40\text{A}$, $V_D = 3400\text{V}$	—	—	10	μs
t_{gq}	Turn-off time	$T_j = 125^\circ\text{C}$, $I_{TM} = 4000\text{A}$, $V_{DM} = 3375\text{V}$, $di_{GQ}/dt = -50\text{A}/\mu\text{s}$ $V_{RG} = 17\text{V}$, $C_S = 5.0\mu\text{F}$, $L_S = 0.2\mu\text{H}$	—	—	40	μs
I_{GQM}	Peak gate turn-off current		—	1000	—	A
V_{GT}	Gate trigger voltage	DC METHOD : $V_D = 24\text{V}$, $R_L = 0.1\Omega$, $T_j = 25^\circ\text{C}$	—	—	1.5	V
I_{GT}	Gate trigger current		—	—	4000	mA
$R_{th(j-f)}$	Thermal resistance	Junction to fin	—	—	0.010	$^\circ\text{C}/\text{W}$

PERFORMANCE CURVES

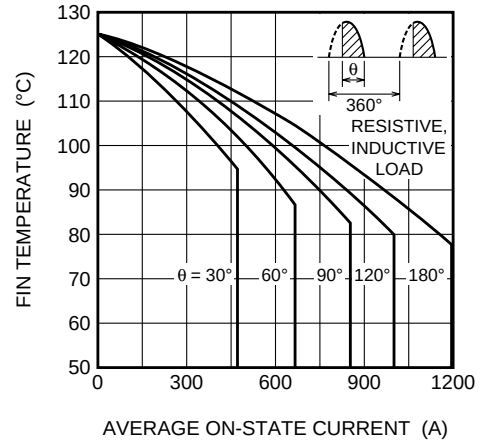
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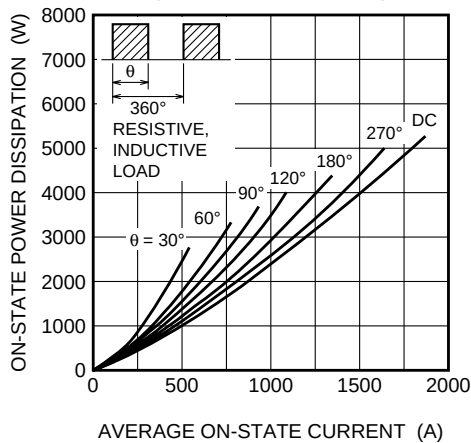
**MAXIMUM ON-STATE POWER DISSIPATION
CHARACTERISTICS
(SINGLE-PHASE HALF WAVE)**



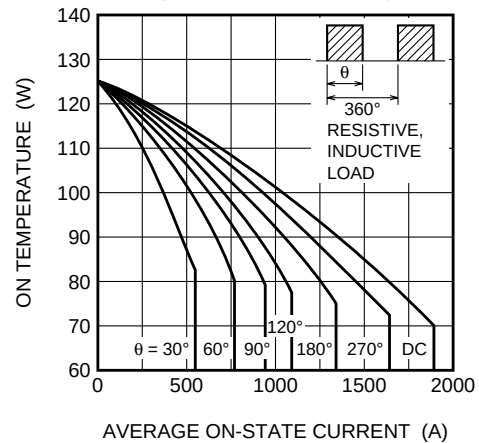
**ALLOWABLE FIN TEMPERATURE VS.
AVERAGE ON-STATE CURRENT
(SINGLE-PHASE HALF WAVE)**



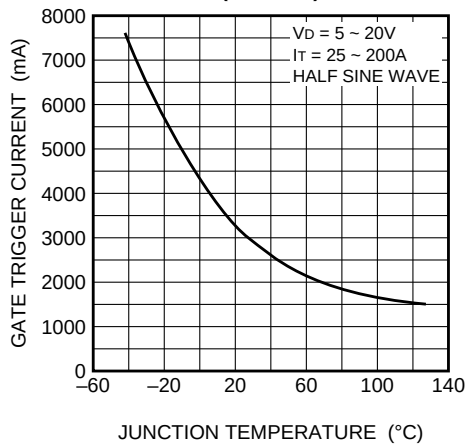
**MAXIMUM ON-STATE POWER DISSIPATION
CHARACTERISTICS
(RECTANGULAR WAVE)**



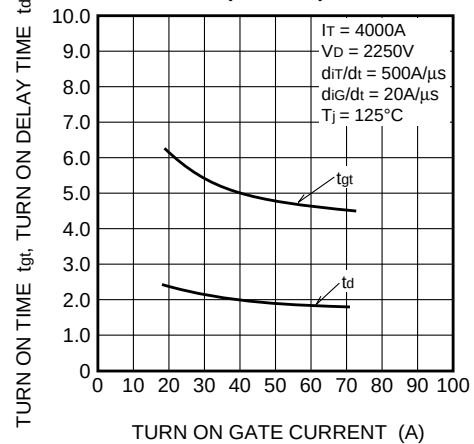
**ALLOWABLE FIN TEMPERATURE VS.
AVERAGE ON-STATE CURRENT
(RECTANGULAR WAVE)**



**GATE TRIGGER CURRENT VS.
JUNCTION TEMPERATURE
(TYPICAL)**



**TURN ON TIME, TURN ON DELAY TIME
VS. TURN ON GATE CURRENT
(TYPICAL)**



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